

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
SA18-11SEKWA	Super Bright Orange (AlGaInP)	White Diffused	88000	400000	Common Anode ,Rt. Hand Decimal.

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Orange	610		nm	I _F =20mA
λ_D [1]	Dominant Wavelength	Super Bright Orange	601		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Orange	29		nm	I _F =20mA
C	Capacitance	Super Bright Orange	15		pF	V _F =0V;f=1MHz
V _F [2]	Forward Voltage Per Segment Or (DP)	Super Bright Orange	6.3 (2.1)	7.5 (2.5)	V	I _F =20mA
I _R	Reverse Current Per Segment Or (DP)	Super Bright Orange		10 (10)	uA	V _R =15V (V _R =5V)

Notes:

1. Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units
Power dissipation Per Segment Or (DP)	225 (75)	mW
DC Forward Current Per Segment Or (DP)	30 (30)	mA
Peak Forward Current [1] Per Segment Or (DP)	195 (195)	mA
Reverse Voltage Per Segment Or (DP)	15 (5)	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature[2]	260°C For 3-5 Seconds	

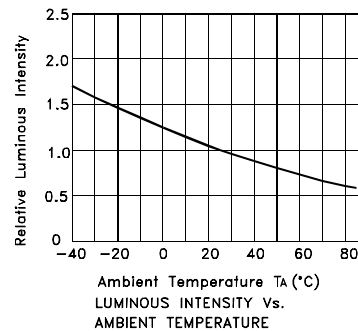
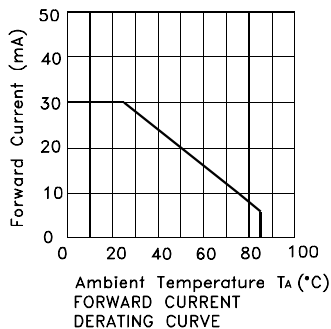
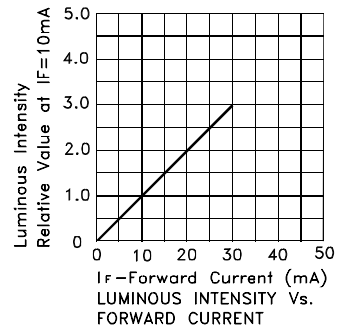
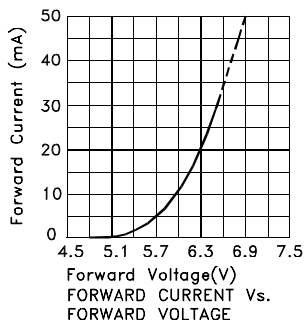
Notes:

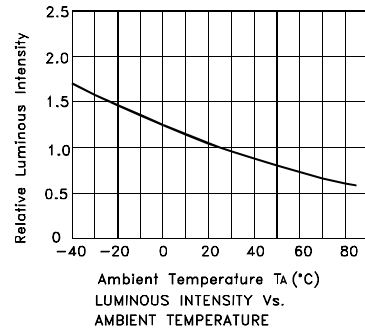
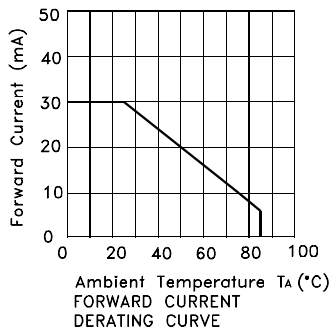
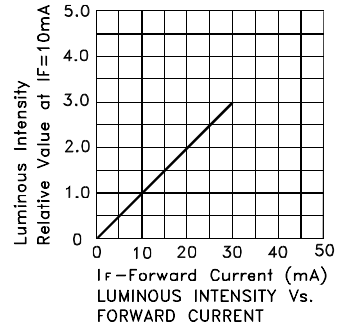
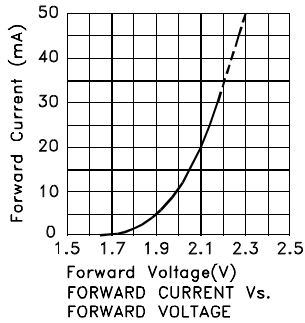
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.



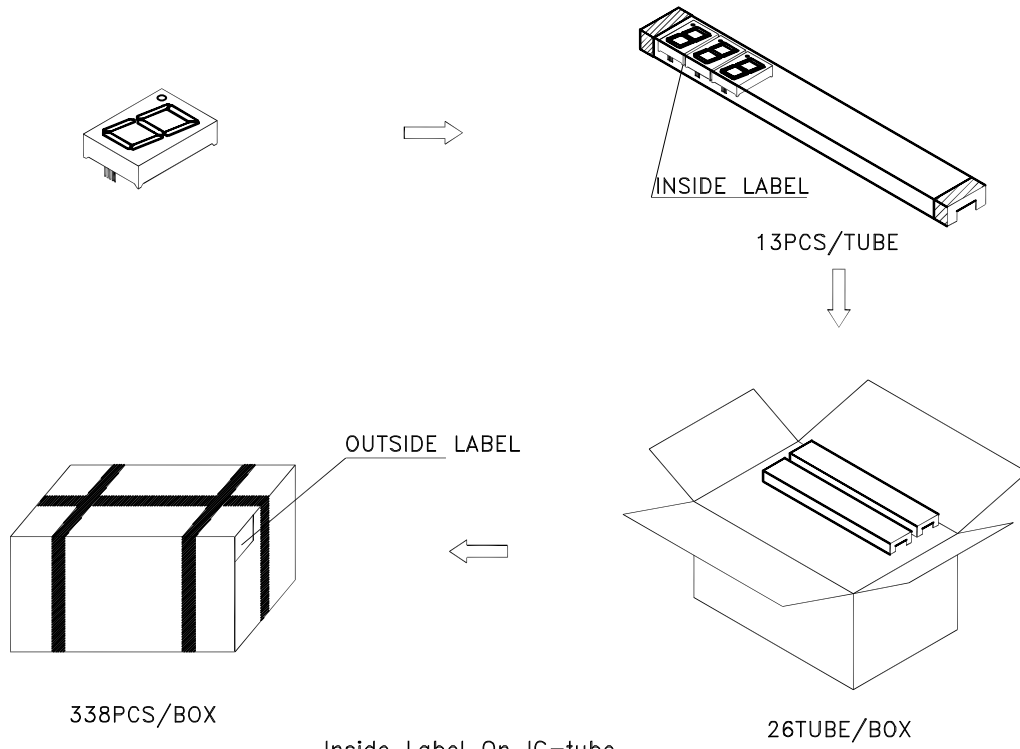
Super Bright Orange SA18-11SEKWA



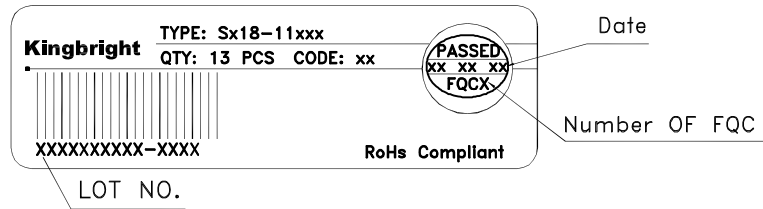


PACKING & LABEL SPECIFICATIONS

SA18-11SEKWA



Inside Label On IC-tube



Outside Label On Box

